

Question:

Given that matched **npn transistors** are available with the parameters: $\beta = 50$, $V_{BE}(\text{on}) = 0.6 \text{ V}$, and $V_A = 150 \text{ V}$. These transistors are used in the designs of a two-transistor current source (as shown in **Figure 1**) and a three-transistor current source (as shown in **Figure 2**). Power supplies used to power the current sources are: $V^+ = 7.5 \text{ V}$ and $V^- = -7.5 \text{ V}$.

(a) **Design** a two-transistor current source and a three-transistor current source with $I_{REF} = 0.90 \text{ mA}$ using the npn transistors mentioned above. [4 marks]

(b) **Find the output resistance (R_O)** of the two-transistor current source and the three-transistor current source. [6 marks]

Show clearly all calculations.

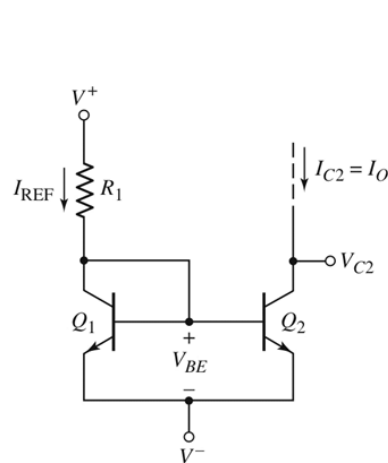


Figure 1

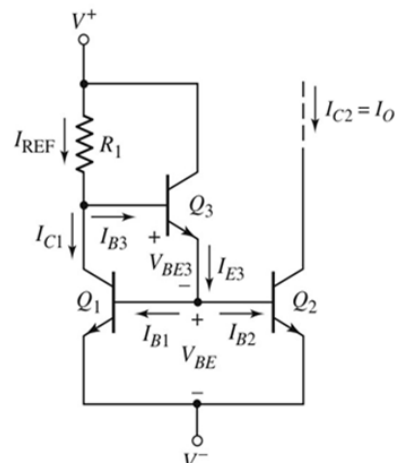


Figure 2

Answer:

2T: $R_1 = (V^+ - V_{EB} - V^-) / I_{REF}$ [1]
 $= (7.5 - 0.6 - (-7.5)) / (0.90\text{m}) = 16.000 \text{ k}\Omega$ [0.5, 0.5]

3T: $R_1 = (V^+ - 2V_{EB} - V^-) / I_{REF}$ [1]
 $= (7.5 - 2(0.6) - (-7.5)) / (0.90\text{m}) = 15.333 \text{ k}\Omega$ [0.5, 0.5]

2T: $I_O = I_{REF} / (1 + 2/\beta)$ [1]
 $= (0.90\text{m}) / (1 + 2/50) = 0.8654 \text{ mA}$ [0.5]
 $R_O = V_A / I_O$ [1]
 $= (150) / (0.8654\text{m}) = 173.333 \text{ k}\Omega$ [0.5]

3T: $I_O = I_{REF} / [1 + 2/\beta(\beta+1)]$ [1]
 $= (0.90\text{m}) / [1 + 2/50(50+1)] = 0.8993 \text{ mA}$ [0.5]
 $R_O = V_A / I_O$ [1]
 $= (150) / (0.8993\text{m}) = 166.797 \text{ k}\Omega$ [0.5]

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(a) **Design** a two-transistor current source and a three-transistor current source with $I_{REF} = 0.95 \text{ mA}$ using the npn transistors mentioned above. [4 marks]

(b) **Find the output resistance (R_O)** of the two-transistor current source and the three-transistor current source. [6 marks]

Show clearly all calculations.

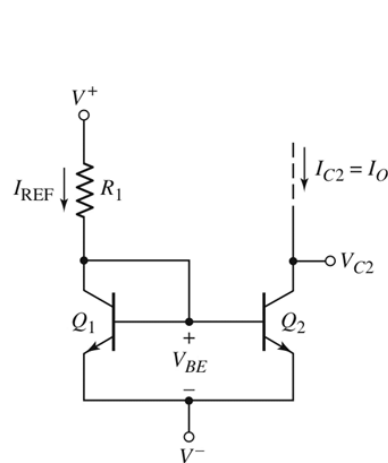


Figure 1

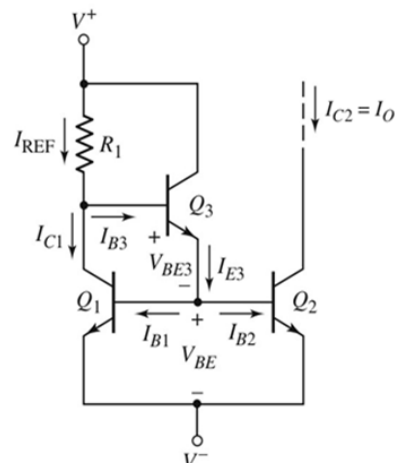


Figure 2

Answer:

2T: $R_1 = (V^+ - V_{EB} - V^-) / I_{REF}$ [1]
 $= (8.5 - 0.6 - (-8.5)) / (0.95\text{m}) = 17.263 \text{ k}\Omega$ [0.5, 0.5]

3T: $R_1 = (V^+ - 2V_{EB} - V^-) / I_{REF}$ [1]
 $= (8.5 - 2(0.6) - (-8.5)) / (0.95\text{m}) = 16.632 \text{ k}\Omega$ [0.5, 0.5]

2T: $I_O = I_{REF} / (1 + 2/\beta)$ [1]
 $= (0.95\text{m}) / (1 + 2/50) = 0.9135 \text{ mA}$ [0.5]
 $R_O = V_A / I_O$ [1]
 $= (150) / (0.9135\text{m}) = 164.211 \text{ k}\Omega$ [0.5]

3T: $I_O = I_{REF} / [1 + 2/\beta(\beta+1)]$ [1]
 $= (0.95\text{m}) / [1 + 2/50(50+1)] = 0.9493 \text{ mA}$ [0.5]
 $R_O = V_A / I_O$ [1]
 $= (150) / (0.9493\text{m}) = 158.019 \text{ k}\Omega$ [0.5]

Question:

Given that matched **npn transistors** are available with the parameters: $\beta = 60$, $V_{BE}(\text{on}) = 0.6 \text{ V}$, and $V_A = 150 \text{ V}$. These transistors are used in the designs of a two-transistor current source (as shown in **Figure 1**) and a three-transistor current source (as shown in **Figure 2**). Power supplies used to power the current sources are: $V^+ = 8.5 \text{ V}$ and $V^- = -8.5 \text{ V}$.

(a) **Design** a two-transistor current source and a three-transistor current source with $I_{REF} = 0.90 \text{ mA}$ using the npn transistors mentioned above. [4 marks]

(b) **Find the output resistance (R_O)** of the two-transistor current source and the three-transistor current source. [6 marks]

Show clearly all calculations.

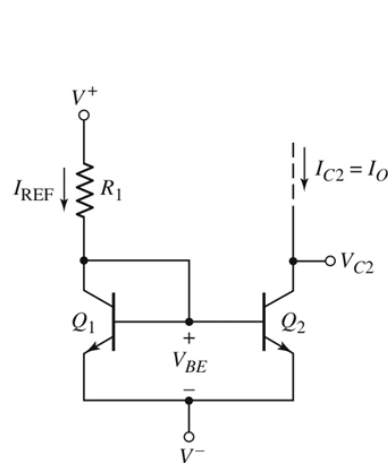


Figure 1

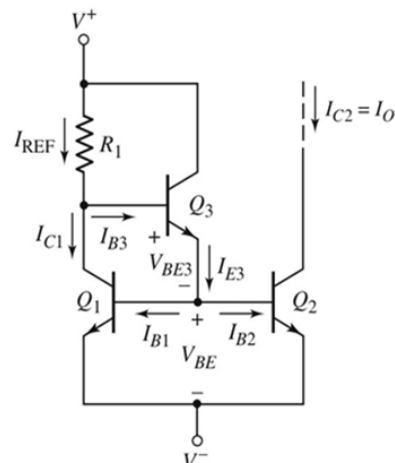


Figure 2

Answer:

2T: $R_1 = (V^+ - V_{EB} - V^-) / I_{REF}$ [1]
 $= (8.5 - 0.6 - (-8.5)) / (0.90\text{m}) = 18.222 \text{ k}\Omega$ [0.5, 0.5]

3T: $R_1 = (V^+ - 2V_{EB} - V^-) / I_{REF}$ [1]
 $= (8.5 - 2(0.6) - (-8.5)) / (0.90\text{m}) = 17.556 \text{ k}\Omega$ [0.5, 0.5]

2T: $I_O = I_{REF} / (1 + 2/\beta)$ [1]
 $= (0.90\text{m}) / (1 + 2/60) = 0.8710 \text{ mA}$ [0.5]

$R_O = V_A / I_O$ [1]
 $= (150) / (0.8710\text{m}) = 172.222 \text{ k}\Omega$ [0.5]

3T: $I_O = I_{REF} / [1 + 2/\beta(\beta+1)]$ [1]
 $= (0.90\text{m}) / [1 + 2/60(60+1)] = 0.8995 \text{ mA}$ [0.5]

$R_O = V_A / I_O$ [1]
 $= (150) / (0.8995\text{m}) = 166.758 \text{ k}\Omega$ [0.5]

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Given that matched **npn transistors** are available with the parameters: $\beta = 60$, $V_{BE}(\text{on}) = 0.6 \text{ V}$, and $V_A = 150 \text{ V}$. These transistors are used in the designs of a two-transistor current source (as shown in **Figure 1**) and a three-transistor current source (as shown in **Figure 2**). Power supplies used to power the current sources are: $V^+ = 7.5 \text{ V}$ and $V^- = -7.5 \text{ V}$.

(a) **Design** a two-transistor current source and a three-transistor current source with $I_{REF} = 0.95 \text{ mA}$ using the npn transistors mentioned above. [4 marks]

(b) **Find the output resistance (R_O)** of the two-transistor current source and the three-transistor current source. [6 marks]

Show clearly all calculations.

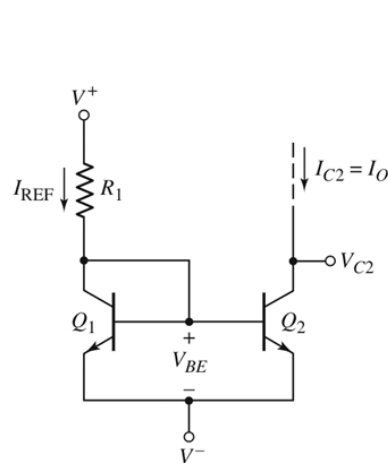


Figure 1

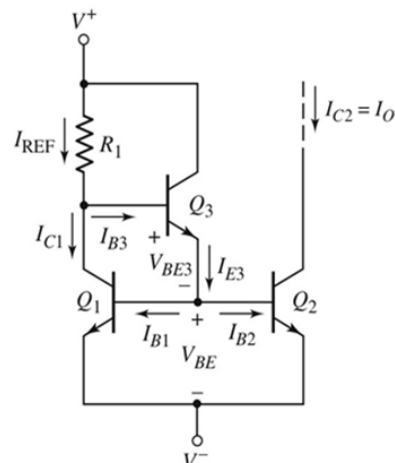


Figure 2

Answer:

2T: $R_1 = (V^+ - V_{EB} - V^-) / I_{REF}$ [1]
 $= (7.5 - 0.6 - (-7.5)) / (0.95\text{m}) = 15.158 \text{ k}\Omega$ [0.5, 0.5]

3T: $R_1 = (V^+ - 2V_{EB} - V^-) / I_{REF}$ [1]
 $= (7.5 - 2(0.6) - (-7.5)) / (0.95\text{m}) = 14.526 \text{ k}\Omega$ [0.5, 0.5]

2T: $I_O = I_{REF} / (1 + 2/\beta)$ [1]
 $= (0.95\text{m}) / (1 + 2/60) = 0.9194 \text{ mA}$ [0.5]
 $R_O = V_A / I_O$ [1]
 $= (150) / (0.9194\text{m}) = 163.158 \text{ k}\Omega$ [0.5]

3T: $I_O = I_{REF} / [1 + 2/\beta(\beta+1)]$ [1]
 $= (0.95\text{m}) / [1 + 2/60(60+1)] = 0.9495 \text{ mA}$ [0.5]
 $R_O = V_A / I_O$ [1]
 $= (150) / (0.9495\text{m}) = 157.981 \text{ k}\Omega$ [0.5]